## NSN 5961-01-096-8158

No Fiig: A110a0



Transistor - Page 1 of 1 View Online at https://aerobasegroup.com/nsn/5961-01-096-8158 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** Between 0.530 inches and 0.560 inches **Overall Diameter:** Between 0.350 inches and 0.370 inches **Internal Configuration:** Field effect **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 90.0 drain to gate voltage and 90.0 drain to source voltage and 30.0 gate to source voltage **Current Rating Per Characteristic:** 2.00 amperes drain current **Power Rating Per Characteristic:** 8.33 watts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 150.0 degrees celsius junction **Test Data Document:** 97942-584r577 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: